TOSHIBA Intelligent Power Module Silicon N Channel IGBT

MIG100Q201H

High Power Switching Applications Motor Control Applications

- Integrates inverter, brake power circuits & control circuits (IGBT drive units, protection units for over-current, under-voltage & over-temperature) in one package.
- The electrodes are isolated from case.
- High speed type IGBT : $V_{CE (sat)} = 3.5 \text{ V (Max.)}$

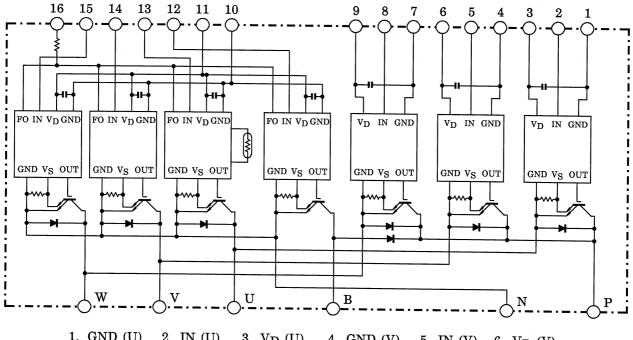
 $t_{off} = 2.5 \mu s$ (Max.)

 $t_{rr} = 0.21 \ \mu s \ (Max.)$

• Outline: TOSHIBA 2-136A1A

• Weight:

Equivalent Circuit



1. GND (U) 2. IN (U) 7. GND (W) 8. IN (W)

3. V_D (U) 9. V_D (W) 4. GND (V) 10.GND (L) 5. IN (V) 6. V_D (V)

13.IN (X) 1

14.IN (Y)

15.IN(Z)

16.FO

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 $11.V_{D}$ (L) 12.IN (B)

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Maximum Ratings ($T_j = 25$ °C)

Stage	Characteristic	Condition	Symbol	Ratings	Unit
Inverter	Supply voltage	P-N power terminal	V _{CC}	900	V
	Collector-emitter voltage	_	V _{CES}	1200	V
	Collector current	$T_C = 25^{\circ}C$, DC	Ic	100	Α
ilivertei	Forward current	T _C = 25°C, DC	IF	100	Α
	Collector power dissipation	T _C = 25°C	PC	800	W
	Junction temperature	_	Tj	150	°C
	Supply voltage	P-N power terminal	V _{CC}	900	V
	Collector-emitter voltage	_	V _{CES}	1200	V
Brake	Collector current	T _C = 25°C, DC	Ic	50	Α
	Reverse voltage	_	V _R	1200	V
	Forward current	T _C = 25°C, DC	l _F	50	Α
	Collector power dissipation	T _C = 25°C	PC	400	W
	Junction temperature	_	Tj	150	°C
Control	Control supply voltage	V _D -GND terminal	V _D	20	V
	Input voltage	IN-GND terminal	V _{IN}	20	V
	Fault output voltage	FO-GND (L) terminal	V _{FO}	20	V
	Fault output current	FO sink current	I _{FO}	14	mA
	Operating temperature	_	TC	-20 ~ +100	°C
Module	Storage temperature range	_	T _{stg}	-40 ~ +125	°C
	Isolation voltage	AC 1 minute	V _{ISO}	2500	V
	Screw torque	M5	_	3	N·m

Electrical Characteristics ($T_j = 25$ °C)

a. Inverter Stage

Characteristic	Symbol	Test Condition		Min	Тур.	Max	Unit
Collector cut-off current	I _{CEX}	V _{CE} = 1200 V	T _j = 25°C	_	_	1	mA
Conector cut-on current			T _j = 125°C	_	_	20	
Collector-emitter saturation	V _{CE (sat)}	$V_D = 15 \text{ V}, I_C = 100 \text{ A}$ $V_{IN} = 3 \text{ V} \rightarrow 0 \text{ V}$	T _j = 25°C	_	2.7	3.5	V
voltage			T _j = 125°C	_	2.6	_	
Forward voltage	V _F	I _F = 100 A		_	2.0	2.7	٧
	t _{on}	V_{CC} = 600 V, I_{C} = 100 A V_{D} = 15 V, V_{IN} = 3 V \leftrightarrow 0 V Inductive load (Note 1)		0.8	1.5	2.2	μs
	t _{o(on)}			_	0.5	1.0	
Switching time	t _{rr}			_	0.14	0.21	
	t _{off}			_	1.5	2.5	
	t _{c(off)}		·	_	0.3	0.6	

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b. Brake Stage

Characteristic	Symbol	Test Condition		Min	Тур.	Max	Unit
Collector cut-off current	ICEX	V _{CE} = 1200V	T _j = 25°C	_	_	1	mA
Conector cut-on current			T _j = 125°C	_	_	20	
Collector-emitter saturation voltage	V _{CE (sat)}	$V_D = 15V, I_C = 50A$ $V_{IN} = 3V \rightarrow 0V$	T _j = 25°C	_	2.7	3.5	V
			T _j = 125°C	_	2.6	_	
Reverse current	I _R	V _R = 1200V	T _j = 25°C	_	_	1	mA
Reverse current			T _j = 125°C	_	_	20	
Forward voltage	V _F	I _F = 50A		_	2.0	2.7	V
	t _{on}	V_{CC} = 600V, I_C = 50A V_D = 15V, V_{IN} = 3V \leftrightarrow 0V Inductive load		0.8	1.5	2.2	-
	t _{c(on)}			_	0.5	1.0	
Switching time	t _{rr}			_	0.30	0.45	μs
	t _{off}	(Note 1)	_	1.5	2.5		
	t _{c(off)}	1	·	_	0.3	0.6	

c. Control Stage ($T_j = 25$ °C)

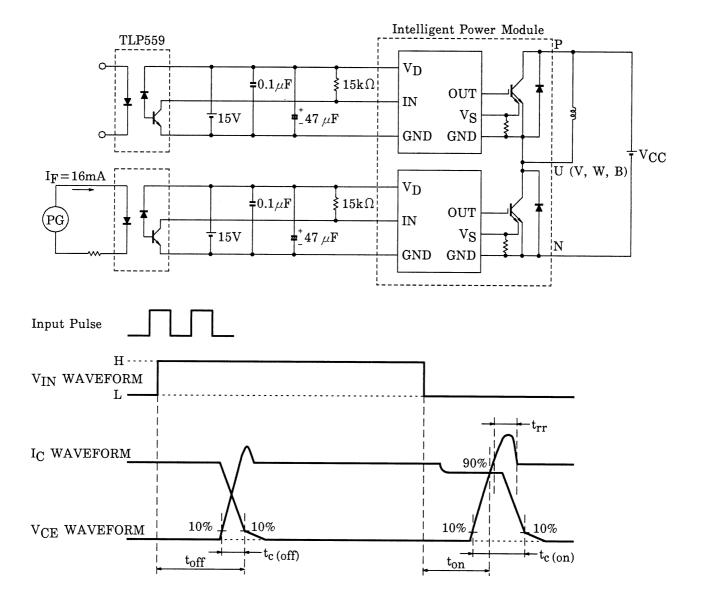
Characteristic		Symbol	Test Condition	Min	Тур.	Max	Unit
Control circuit current	High side	I _{D (H)}	V _D = 15 V	_	20	30	mA
	Low side	I _{D (L)}		_	80	120	
Input-on signal voltage		V _{IN (on)}	V _D = 15 V, I _C = 100 mA	0.9	1.1	1.3	٧
Fault output current	Protection	I _{FO (on)}	- V _D = 15 V	8	10	12	mA
	Normal	I _{FO (off)}		_	_	1	
Over current protection trip level	Inverter	00	V _D = 15 V, T _j = 125°C	160	200	_	А
	Brake	OC		70	100	_	
Short current protection trip level	Inverter	0.0	V _D = 15 V, T _j = 125°C	240	300	_	
	Brake	SC		105	150	_	Α
Over current cut-off time		t _{off (OC)}	V _D = 15 V	_	10	_	μs
Over temperature protection	Trip level	ОТ	0	111	118	125	°C
	Reset level	OTr	Case temperature	93	100	107	C
Control supply under voltage protection	Trip level	UV		11.3	12.0	12.7	.,
	Reset level	UVr		11.8	12.5	13.2	V
Fault output pulse width		t _{FO}	V _D = 15 V	1	2	3	ms

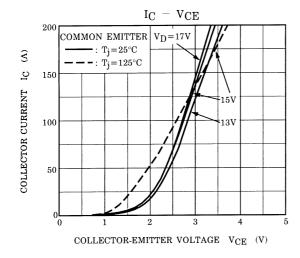
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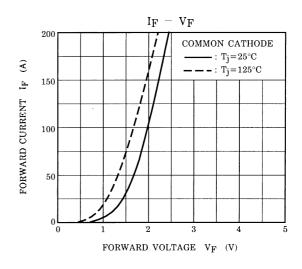
d. Thermal Resistance ($T_j = 25$ °C)

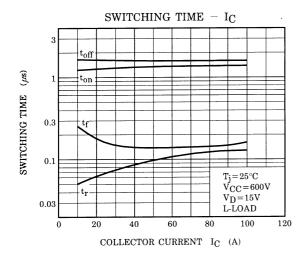
Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
	R _{th (j-c)}	Inverter IGBT	_	_	0.156	·°C/W
Junction to case thermal resistance		Inverter FRD	1	1	0.50	
		Brake IGBT	_	_	0.312	
		Brake FRD	_	_	1.00	
Case to fin thermal resistance	R _{th (c-f)}	Compound is applied	-	0.04	_	°C/W

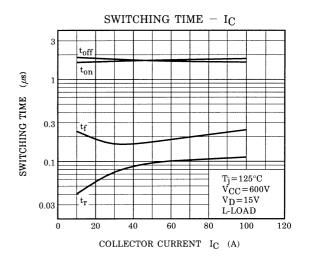
Note 1 : Switching time test circuit & timing chart

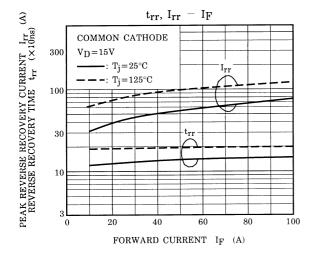


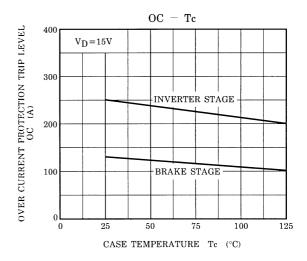


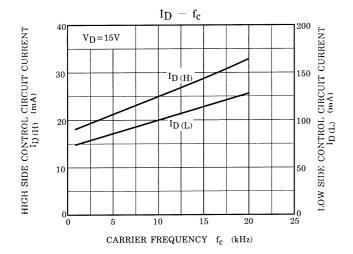


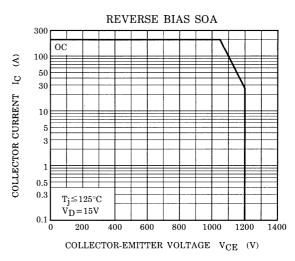


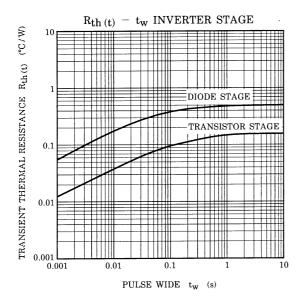


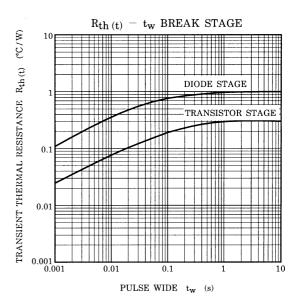








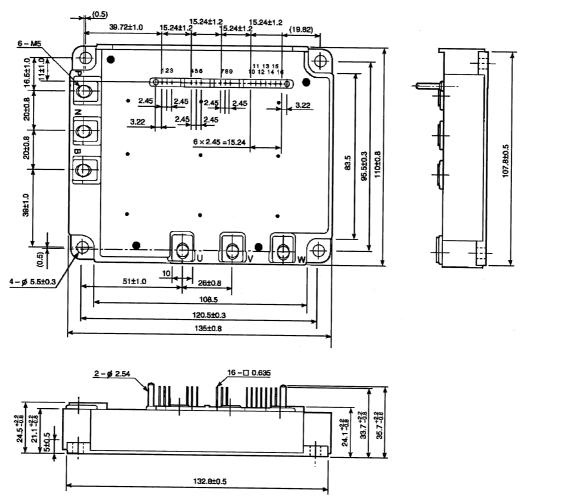




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Package Dimensions: TOSHIBA 2-136A1A

Unit: mm



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